

SHM-12 Ultra-Fast, 12-Bit Linear Monolithic Sample-Hold Amplifiers

FEATURES

- Fast acquisition time:
 - 10ns to ±0.1% 15ns to ±0.024% 20ns to ±0.012%
- ±0.006% Nonlinearity
- 65µVrms output noise
- 120MHz small signal bandwidth
- 55MHz full power bandwidth
- –80dB feedthrough
- 1ps Aperture jitter
- 250mW power dissipation
- · Low cost

GENERAL DESCRIPTION

The SHM-12 is an extremely high-speed and accurate monolithic sample-and-hold amplifier designed for fast data acquisition applications. The SHM-12 is accurate (\pm 1LSB at 12 bits over the full military temperature range) and is very fast (10ns and 15ns acquisition times to accuracies of 10 and 12-bits, respectively). With this high performance and a full power bandwidth of 55MHz, the SHM-12 is an ideal device for driving flash and high-resolution subranging A/D converters.

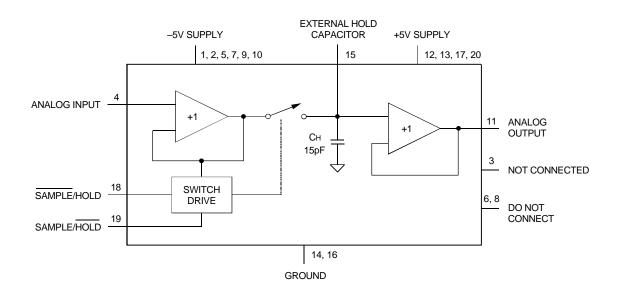
A careful design optimizes the device for accuracy and speed over the full military temperature range. The droop rate is a low $\pm 0.5 \text{mV/}\mu\text{s}$. The 30mA output current and guaranteed specifications for a 100 Ω load provide high drive capability. Operating from $\pm 5\text{V}$ supplies, the SHM-12 consumes only 250mW of power.



INPUT/OUTPUT CONNECTIONS (CLCC and SOIC-20 Packages)

PIN	FUNCTION	PIN	FUNCTION
1	-5V SUPPLY	20	+5V SUPPLY
2	-5V SUPPLY	19	SAMPLE/HOLD
3	NOT CONNECTED	18	SAMPLE/HOLD
4	ANALOG INPUT	17	+5V SUPPLY
5	-5V SUPPLY	16	GROUND
6	DO NOT CONNECT	15	EXT. CAPACITOR
7	-5V SUPPLY	14	GROUND
8	DO NOT CONNECT	13	+5V SUPPLY
9	-5V SUPPLY	12	+5V SUPPLY
10	-5V SUPPLY	11	ANALOG OUTPUT

The SHM-12 is built using a fast complementary bipolar process. The device is available in both military and industrial temperature ranges. The SHM-12 is packaged in a 20-pin plastic SOIC or ceramic LCC.





ABSOLUTE MAXIMUM RATINGS

PARAMETERS	LIMITS	UNITS		
+5V Supply	0 to +6	Volts		
-5V Supply	0 to -6	Volts		
Analog Input	+5V Supply –1	Volts		
	-5V Supply +1	Volts		
Continuous Output Current	±50	mA		
Digital Inputs	<supply th="" voltages<=""><th>Volts</th></supply>	Volts		
Junction Temperature	+175	°C		
Lead Temperature (10 seconds)	+300	°C		
Output shorted to any supply will cause permanent damage.				

FUNCTIONAL SPECIFICATIONS

(Apply over the operating temperature range using a 100 Ω resistive load, 10pF capacitive load, ECL digital input levels, a 47pF external hold capacitor, and $\pm 5V$ nominal supplies, unless otherwise specified.)

INPUTS MII Input Voltage Range -1. Input Impedance 0.3 Digitals Inputs (Balanced ECL) 0.3 Logic Levels -1. Logic 1 -1. Logic 0 -2. Logic Loading - Logic 0 - OUTPUTS - Output Voltage Range -1. Output Current ① ± 3 Output Impedance (dc) - Stable Capacitive Load - PERFORMANCE - Nonlinearity (±1V) +25°C -55 to +125°C - Sample Mode Offset - +25°C -	5 3 5 5 5 - - - 5 0	TYP. 1 +10 30 0.3 ±0.006 	MAX. +1.5 - +1.8 +0.8 +50 -150 +1.5 - 1 50 +1.5 - 1 50	UNITS Volts MΩ Volts Volts Wolts mA Ω pF % % %
Injuit Impedance 0.3 Digitals Inputs (Balanced ECL) 0.3 Logic Levels -1 Logic 0 -2. Logic Loading -2 Logic 0 -2 Output Corrent © -3 Output Voltage Range -1. Output Voltage Range -1. Output Current © ± 3 Output Impedance (dc) - Stable Capacitive Load - PERFORMANCE - Nonlinearity (±1V) +25°C -55 to +125°C - -55 to 4125°C -	5 5 5 - -			MΩ Volts Volts μA μA Volts mA Ω pF
Digitals Inputs (Balanced ECL)	.5 .5		+0.8 +50 -150 +1.5 - 1 50 	Volts Volts μA μA Volts mA Ω pF
Logic Levels -1. Logic 0 -2. Logic 1 -1. Logic 0 -2. Logic Loading -2. Logic 0 - OUTPUTS	.5 .5 .0	-30 	+0.8 +50 -150 +1.5 - 1 50 	Volts μA μA Volts mA Ω pF
Logic 1 -1. Logic 0 -2. Logic Loading -2. Logic 1 - Logic 0 - OUTPUTS - Output Voltage Range -1. Output Current ① ± 3 Output Impedance (dc) - Stable Capacitive Load - PERFORMANCE - Nonlinearity (±1V) +25°C -40 to +85°C - -55 to +125°C - Sample Mode Offset -	.5 .5 .0	-30 	+0.8 +50 -150 +1.5 - 1 50 	Volts μA μA Volts mA Ω pF
Logic 0 -2. Logic Loading	.5 .5 .0	-30 	+0.8 +50 -150 +1.5 - 1 50 	Volts μA μA Volts mA Ω pF
Logic Loading	5	-30 	+50 -150 +1.5 - 1 50 ±0.024	μΑ μΑ Volts mA Ω pF
Logic 1 Logic 0 OUTPUTS Output Voltage Range 1. Output Current ① ± 3 Output Impedance (dc) Stable Capacitive Load PERFORMANCE Nonlinearity (±1V) +25°C -40 to +85°C -55 to +125°C Sample Mode Offset	0	-30 	-150 +1.5 - 1 50 ±0.024	μΑ Volts mA Ω pF
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OUTPUTS Output Voltage Range -1. Output Current ① ± 3 Output Impedance (dc) Stable Capacitive Load PERFORMANCE Nonlinearity (±1V) +25°C -40 to +85°C -55 to +125°C Sample Mode Offset	0	 0.3 	+1.5 1 50 ±0.024	Volts mA Ω pF %
Output Voltage Range -1. Output Current ① ± 3 Output Impedance (dc) - Stable Capacitive Load - PERFORMANCE - Nonlinearity (±1V) +25°C -40 to +85°C - -55 to +125°C - Sample Mode Offset -	0	0.3	1 	mA Ω pF %
Output Current ① \pm 3 Output Impedance (dc) - Stable Capacitive Load - PERFORMANCE - Nonlinearity (\pm 1V) +25°C -40 to +85°C - -55 to +125°C - Sample Mode Offset -	0	0.3	1 	mA Ω pF %
Output Impedance (dc) Stable Capacitive Load PERFORMANCE Nonlinearity (±1V) +25°C -40 to +85°C -55 to +125°C Sample Mode Offset		0.3	50 ±0.024	Ω pF %
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+25°C — -40 to +85°C — -55 to +125°C — Sample Mode Offset	-	±0.006 		%
-40 to +85°C		±0.006 — —		%
-55 to +125°C — Sample Mode Offset		_		
Sample Mode Offset	-	—	±0.024	%
				70
+25°C				
	-	±12	_	mV
-40 to +85°C —	-	—	±20	mV
_55 to +125°C —	-	—	±30	mV
Pedestal				.,
+25°C —	-	±3	- 20	mV
-40 to +85°C -	-	_	±20	mV
_55 to +125°C Gain, +25°C	- 00	+0.995	±20	mV
	70	+0.995	_	V/V
Gain Drift (±1V) -40 to +85°C —			±20	ppm/°C
-40 to +85 C	-	_	±20 ±30	
Aperture Delay	-	_	±30	ppm/°C
-40 to +85°C		2		ns
-40 to +85 C		2		ns
Aperture Jitter		2		113
-40 to +85°C		1		ps rms
-55 to +125°C		1		ps rms
Harmonic Distortion (±1V)				P3 1113
dc to 1MHz		-75	_	dB
dc to 10MHz				
+25°C	-	-62	_	dB
-40 to +85°C	-	_	-56	dB
–55 to +125°C —	-	_	-54	dB
Acquisition Time (±0.012%, ±1V)				
-40 to +85°C	-	20	—	ns
–55 to +125°C —	-	30	_	ns
Acquisition Time (±0.024%, ±1V)				
-40 to +85°C —	-	15	30	ns
–55 to +125°C —	-	25	40	ns
Acquisition Time (±0.05%, ±1V)				
-40 to +85°C	-	12	25	ns
–55 to +125°C —	-	15	30	ns

PERFORMANCE (Cont.)	MIN.	TYP.	MAX.	UNITS	
Acquisition Time (±0.1%, ±1V)					
-40 to +85°C	_	10	20	ns	
-55 to +125°C	_	10	20	ns	
Hold Mode Settling (±0.012%)			20		
-40 to +85°C	_	10	_	ns	
-55 to +125°C	_	10	_	ns	
Hold Mode Settling (±0.024%)		10		115	
-40 to +85°C	_	7	18	ns	
–40 to +03 C		7	18	ns	
Hold Mode Settling (±0.05%)			10	115	
-40 to +85°C		6	15	ns	
-40 to +85 C	_	6	15		
	_	0	10	ns	
Hold Mode Settling (±0.1%)		F	10		
-40 to +85°C	_	5	12	ns	
–55 to +125°C	_	5	12	ns	
Slew Rate	±220	±350	—	V/µs	
Full Power Bandwidth (±1V)	35	55	—	MHz	
Small Signal Bandwidth	50	120	—	MHz	
Output Noise, Hold Mode	—	65	—	μVrms	
Feedthrough (2V Step)	-	-80	—	dB	
Droop Rate					
+25°C	—	±0.5	±1.5	mV/µs	
-40 to +85°C	_	±2	±5	mV/µs	
–55 to +125°C	_	±2.5	±10	mV/µs	
POWER SUPPLY REQUIREMENTS					
Power Supply Range					
+5V Supply	+4.5	+5	+5.5	Volts	
-5V Supply	-5.5	-5	-4.5	Volts	
Power Supply Current	0.0	5	4.5	VOIG	
+5V Supply	+17	+25	+30	mA	
–5V Supply	-17	-25	-30	mA	
Power Dissipation	170	250	300	mW	
Power Supply Rejection Ratio	40	60	300	dB	
	40	00	_	uБ	
ENVIRONMENTAL	I	1	n	r	
Operating Temp. Range, Case					
SHM-12S, SHM-12L	-40	-	+85	°C	
SHM-12LM	-55	_	+125	°C	
Storage Temperature Range	-65	_	+150	°C	
Package Type					
SHM-12S		20-Pin nl	astic SOIC		
SHM-12L, SHM-12LM			ramic LCC		
Footnotes:	1				

0 Short circuit protection at ±50mA.

TECHNICAL NOTES

The SHM-12 employs an open loop architecture to achieve its superior high-speed characteristics. The first stage buffer amplifier incorporates the sample-and-hold switch. This allows for a fast acquisition time which is not limited by slew current like the traditional Schottky diode bridge switch. The output amplifier uses a closed loop voltage feedback design which provides a low $(0.3\Omega, typical)$ output impedance. Gain and linearity are not affected by heavy loads.

The design has been optimized to achieve the high accuracy associated with fast transient responses over the military temperature range. During the track-to-hold transient, the integral nonlinearity is not affected and the pedestal remains constant over the full $\pm 1.5V$ input range.

An innovative circuit design ensures an extremely low droop rate. An external hold capacitor can be added to the 15pF internal hold capacitor to obtain a lower droop rate (the droop rate is proportional to the inverse of the total hold capacitor value) without increasing transient response times by more than a few ns. The external hold capacitor should not exceed 100pF.





GROUNDING AND LAYOUT

Obtaining fully specified performance from the SHM-12 requires careful attention to pc-board layout and power supply decoupling.

For optimal performance, tie all grounds directly to a large analog ground plane beneath and around the package. Bypass all power supplies to ground with 10μ F tantalum capacitors in parallel with 0.1μ F ceramic capacitors.

Locate the bypass capacitors as close to the unit as possible.

For best performance, controlled impedance transmission line techniques, such as microstrip, should be used. Mount all components as close to the required pins as possible. It is strongly recommended that the SHM-12 not be socket-mounted.

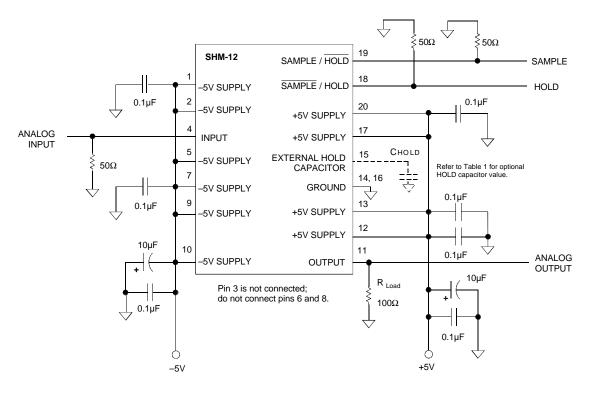


Figure 2. SHM-12 Simplified Connection Diagram

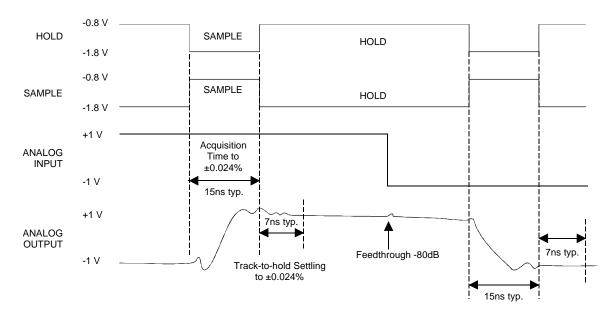


Figure 3. SHM-12 Control and Timing



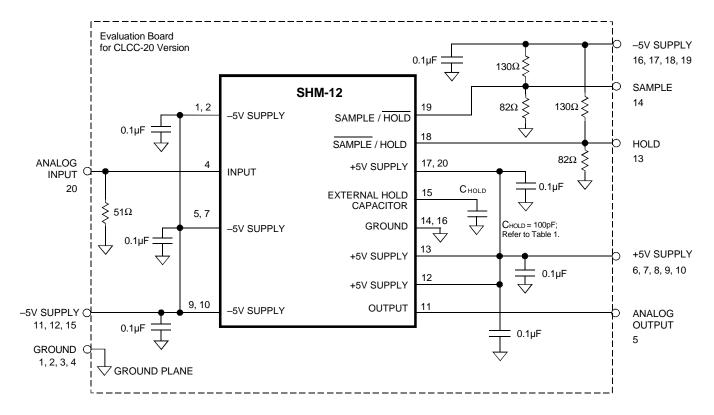
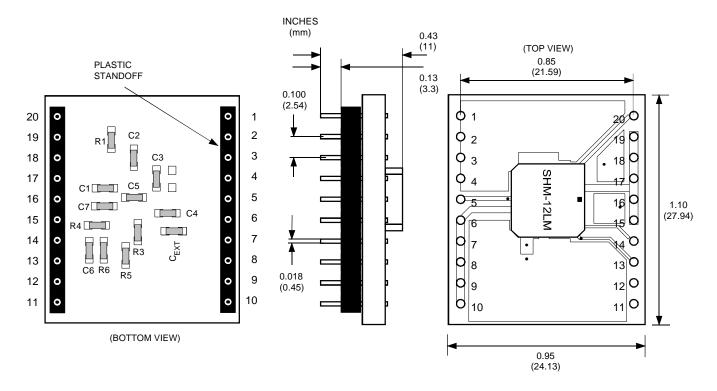


Figure 4. SHM-12 Evaluation Board Schematic

Table 1.	Optional	External HOLD	Capacitor
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Model	Operating Temperature Range	Type of HOLD Capacitor (Ceramic, ≤100pF, ±10%)
SHM-12L, -12S	–40 to +85°C	Type I or II, NPO or X7R
SHM-12LM	–55 to +125°C	Type I or NPO

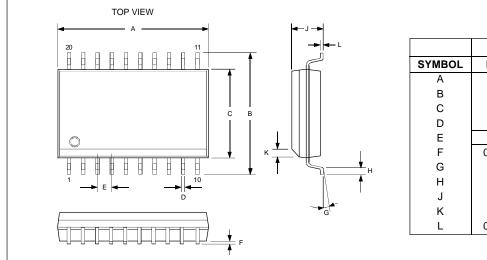




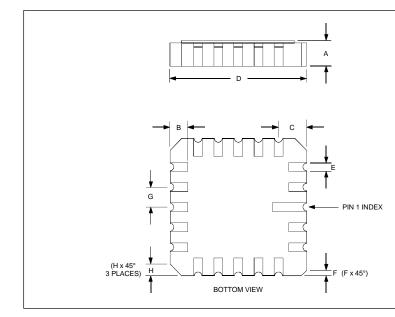
TION	
ND	
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ND	
DG Ol	TPUT
UPPL	
JPPL	
JPPL	
LE	
JPPL	
DG IN	TUT
JPPL JPPL JPPL JPPL	UT

SHM-12 Evaluation Board Connections

MECHANICAL DIMENSIONS



SOIC-20 Package					
	INC	HES	MILLIM	ETERS	
SYMBOL	MIN. MAX.		MIN.	MAX.	
А	0.500	0.510	12.70	12.95	
В	0.400	0.410	10.16	10.41	
С	0.292	0.299	7.40	7.60	
D	0.014	0.019	0.35	0.48	
Е	0.0500 BSC		1.27 BSC		
F	0.0039	0.0112	0.10	0.30	
G	0°	8°	0°	8°	
н	0.020	0.040	0.51	1.02	
J	0.097	0.104	2.46	2.64	
к	0.010	0.020	0.25	0.51	
L	0.0091	0.0125	0.23	0.32	



CLCC-20 Package

	INCHES		MILLIN	IETERS
SYMBOL	MIN.	MAX.	MIN.	MAX.
А	0.064	0.100	1.63	2.54
В	0.045	0.055	1.14	1.40
С	0.075 REF		1.91	REF
D	0.342	0.358	8.69	9.09
Е	0.022	0.028	0.56	0.71
F	0.020 REF		0.5	51
G	0.050 BSC		1.27	BSC
Н	0.040 REF		1.0)2

ORDERING INFORMATION

MODEL NUMBER	PACKAGE	TEMPERATURE RANGE
SHM-12S	SOIC-20	-40 to +85°C
SHM-12L	CLCC-20	-40 to +85°C
SHM-12LM	CLCC-20	-55 to +125°C
EVB-SHM12	Evaluation Boa	ard (with SHM-12LM)

Contact DATEL for availability of high-reliability models.



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